

## 20V P-Channel Enhancement Mode MOSFET - ESD Protected

Voltage -20 V Current -4.3A

#### **Features**

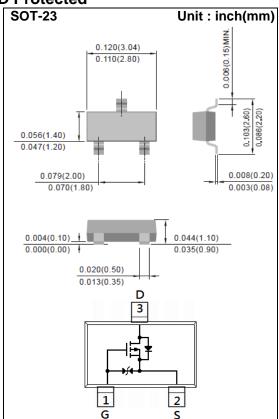
- R<sub>DS(ON)</sub>, V<sub>GS</sub>@-4.5V, I<sub>D</sub>@-4.3A<52mΩ
- R<sub>DS(ON)</sub>, V<sub>GS</sub>@-2.5V, I<sub>D</sub>@-3.0A<60mΩ
- $R_{DS(ON)}$ ,  $V_{GS}@-1.8V$ ,  $I_{D}@-1.5A<80m\Omega$
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected 2KV HBM
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

• Case: SOT-23 Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0003 ounces, 0.0084 grams



# **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage	V <sub>DS</sub>	-20	V		
Gate-Source Voltage	V <sub>GS</sub>	<u>+</u> 8			
Continuous Drain Current		I <sub>D</sub>	-4.3	- A	
Pulsed Drain Current		I <sub>DM</sub>	-17.2		
Power Dissipation	T <sub>a</sub> =25°C	P <sub>D</sub>	1.25	W	
	Derate above 25°C		10	mW/°C	
Operating Junction and Storage Temperature Range		TJ,TSTG	-55~150	°C	
Typical Thermal Resistance					
- Junction to Ambient (Note 3)		Reja	100	°C/W	



### **Electrical Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA	-20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250uA	-0.4	-0.72	-1.0	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-4.3A	-	44	52	mΩ
		V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-3.0A	-	53	60	
		V <sub>GS</sub> =-1.8V, I <sub>D</sub> =-1.5A	-	70	80	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-20V, V <sub>GS</sub> =0V	-	-	-1	uA
Gate-Source Leakage Current	Igss	V <sub>GS</sub> = <u>+</u> 8V, V <sub>DS</sub> =0V	-	-	<u>+</u> 10	
Dynamic (Note 5)						
Total Gate Charge	$Q_g$	\/ 40\/ I 40A	-	24	-	nC
Gate-Source Charge	Qgs	V <sub>DS</sub> =-10V, I <sub>D</sub> =-4.3A,	-	1.5	-	
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =-4.5V (Note 1,2)	-	2.5	-	
Input Capacitance	Ciss	\/ 40\/ \/ 0\/	-	907	-	pF
Output Capacitance	Coss	V <sub>DS</sub> =-10V, V <sub>GS</sub> =0V, f=1.0MHZ	-	90	-	
Reverse Transfer Capacitance	Crss	I=1.UIVIHZ	-	70	-	
Turn-On Delay Time	td <sub>(on)</sub>	101/ 101	-	45	-	
Turn-On Rise Time	tr	V <sub>DD</sub> =-10V, I <sub>D</sub> =-4.3A,	-	79	-	1
Turn-Off Delay Time	td <sub>(off)</sub>	$V_{GS}$ =-4.5V, $R_{G}$ =6 $\Omega$ (Note 1,2)	-	193	-	ns
Turn-Off Fall Time	tf	RG=012 (1686 1,2)	-	826	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	ls		_	-	-1.5	А
Diode Forward Voltage	V <sub>SD</sub>	Is=-1.0A, V <sub>G</sub> s=0V		-0.76	-1.2	V

#### NOTES:

- 1. Pulse width<a></a>300us, Duty cycle<a></a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited
- 5. Guaranteed by design, not subject to production testing.



#### **TYPICAL CHARACTERISTIC CURVES**

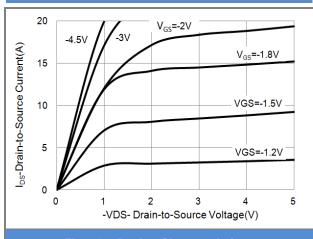


Fig.1 On-Region Characteristics

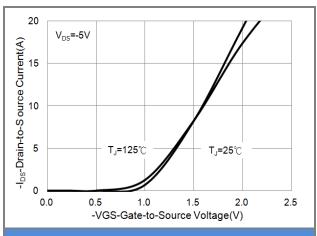


Fig.2 Transfer Characteristics

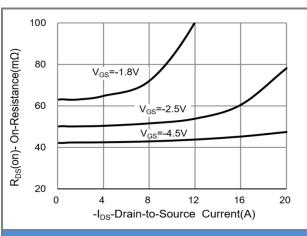


Fig.3 On-Resistance vs. Drain Current

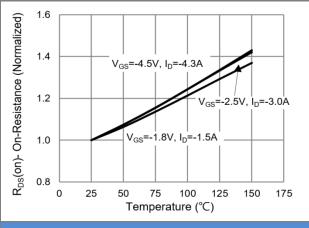
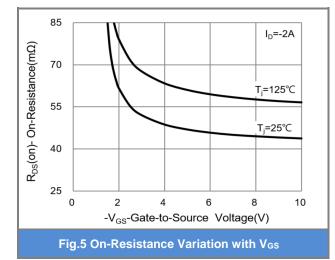
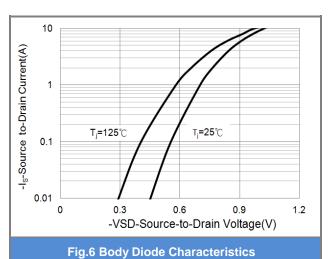


Fig.4 On-Resistance vs. Junction temperature





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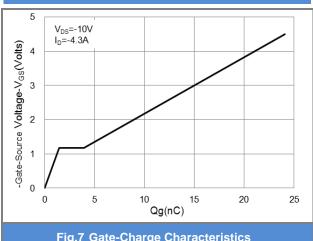


Fig.7 Gate-Charge Characteristics

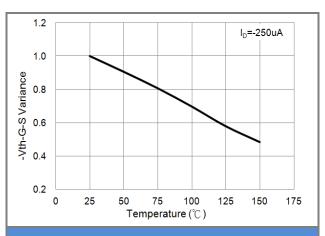


Fig.8 Threshold Voltage Variation with Temperature

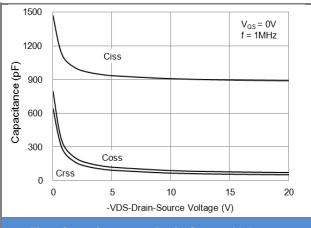


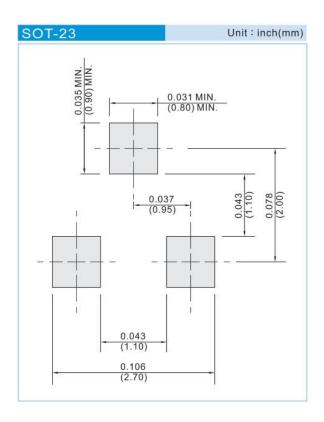
Fig.9 Capacitance vs. Drain-Source Voltage



# **Product and Packing Information**

Part No.	Package Type	Packing Type	Marking
PJA3415AE-AU	SOT-23	3K pcs / 7" reel	A5AE

# **Mounting Pad Layout**





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